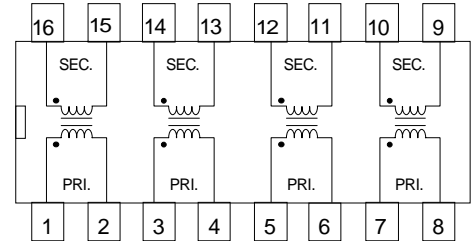


WIDE BAND TRANSFORMER

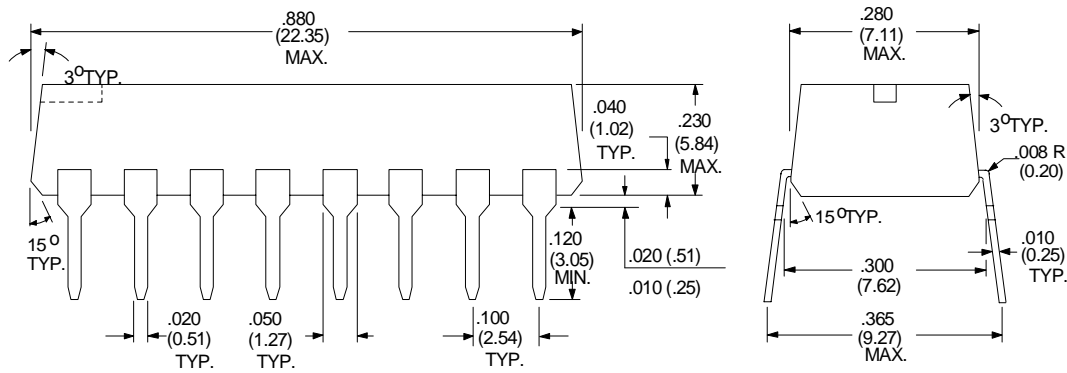
Turns Ratio ($\pm 2\%$)		1 : 1.6		
PARAMETER	MIN.	TYP.	MAX.	UNITS
Inductance ⁽¹⁾ Primary		20		μH
Leakage Inductance		40		nH
DC Resistance Primary		0.140		ohms
DC Resistance Secondary		0.198		ohms
Interwinding Capacitance		12.5		pF
Hi-pot	500			Vrms

Schematic Diagram



1. Tested at 4 MHz & 1 V

Physical Dimensions
inches (mm)



RHOMBUS P/N: T-1200-1

CUST P/N:

NAME:

DATE: 4/19/99

SHEET: 1 of 1